

Supplementary information

Electrochemically activated copper-based catalyst from coordination polymer for stable hydrogen evolution reaction

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Supplementary Figures

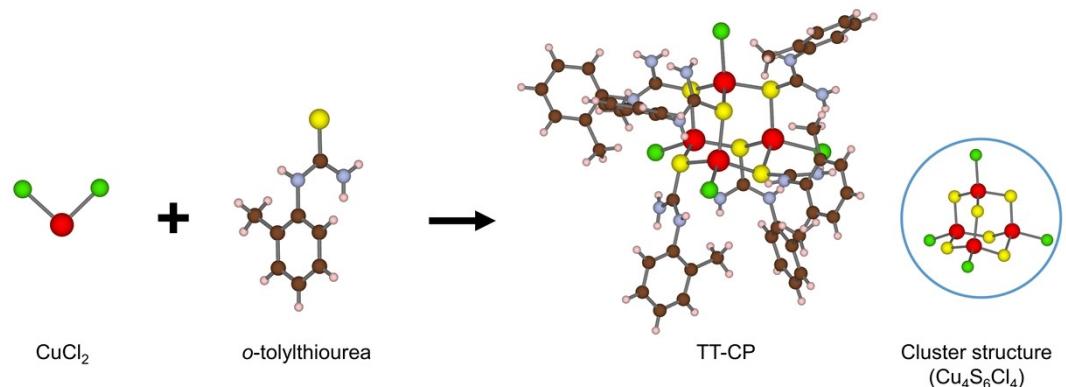


Fig. S1 Schematic illustration showing the fabrication process of TT-CP by mixing CuCl_2 and *o*-tolylthiourea.

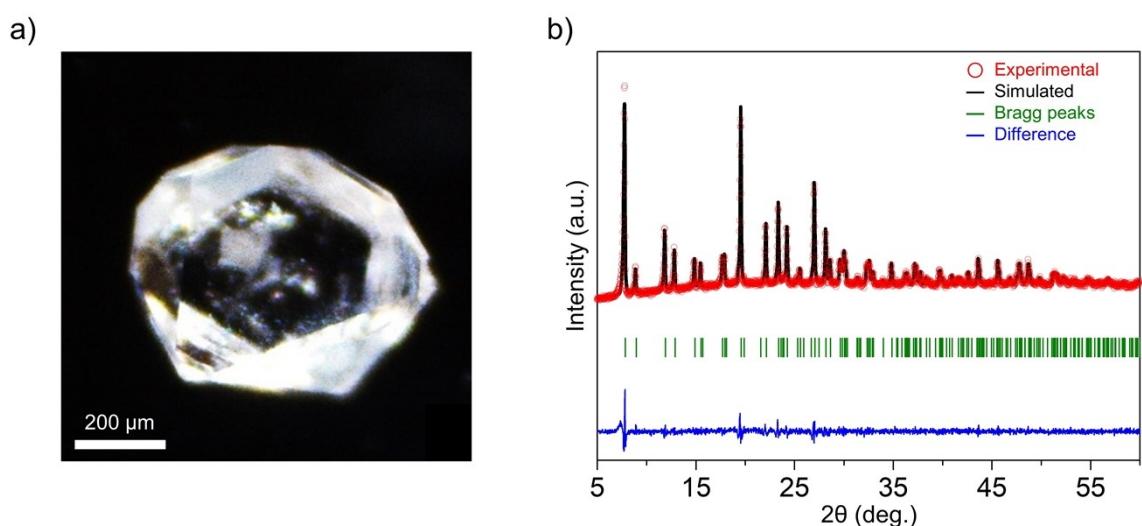


Fig. S2 (a) Optical microscope image of a TT-CP single crystal. (b) Rietveld refinement result of micrometer-scale TT-CP powders.

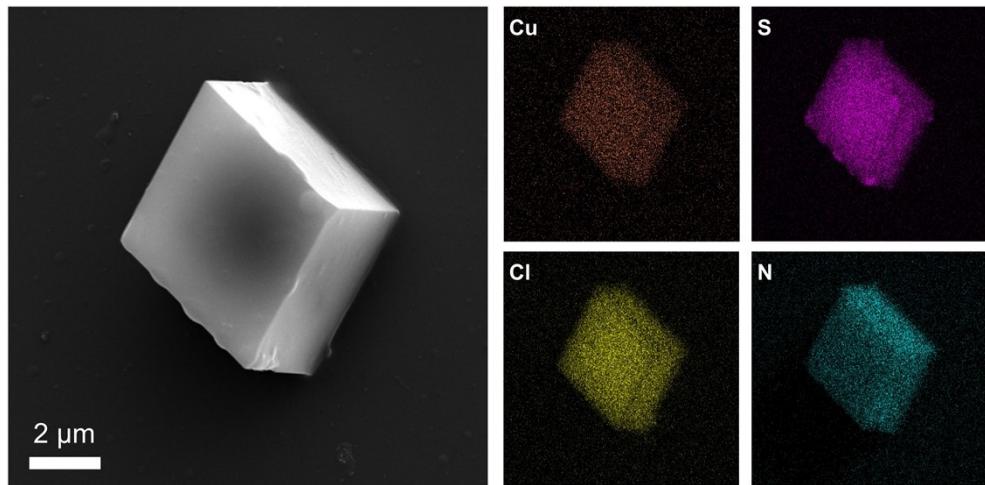


Fig. S3 SEM image and EDS mapping result of a single TT-CP micrometer-scale powder, where the Cu, S, Cl, C, and N elements are detected.

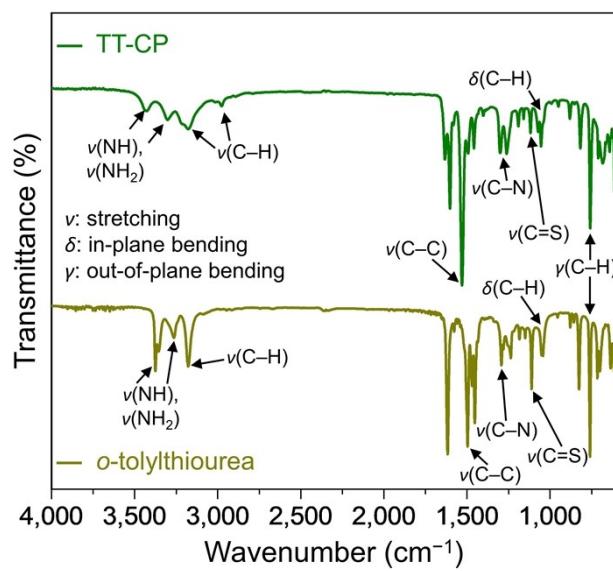


Fig. S4 FT-IR spectra of *o*-tolylthiourea and TT-CP.

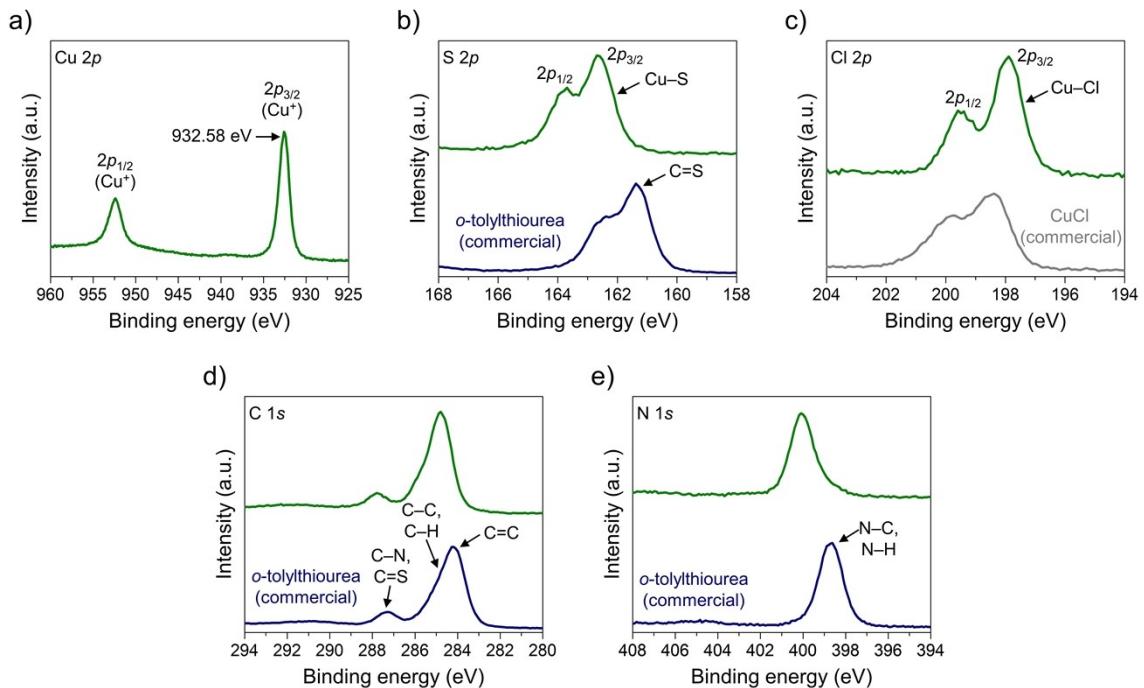


Fig. S5 XPS spectra of TT-CP measured at the core level region of (a) Cu 2p, (b) S 2p, (c) Cl 2p, (d) C 1s, and (e) N 1s.

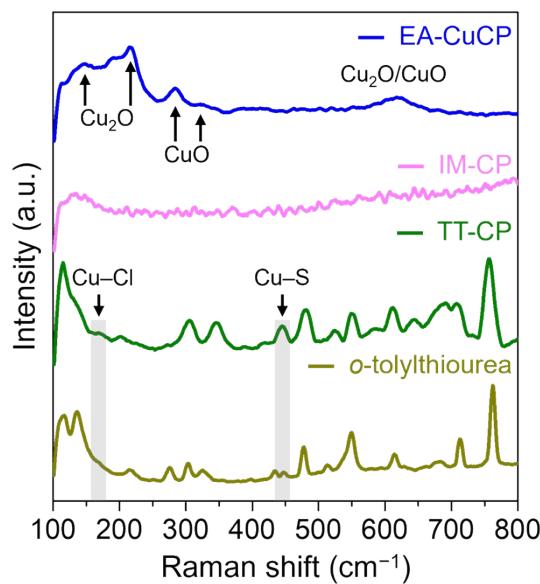


Fig. S6 Raman spectra of *o*-tolylthiourea, TT-CP, IM-Cu, and EA-CuCP.

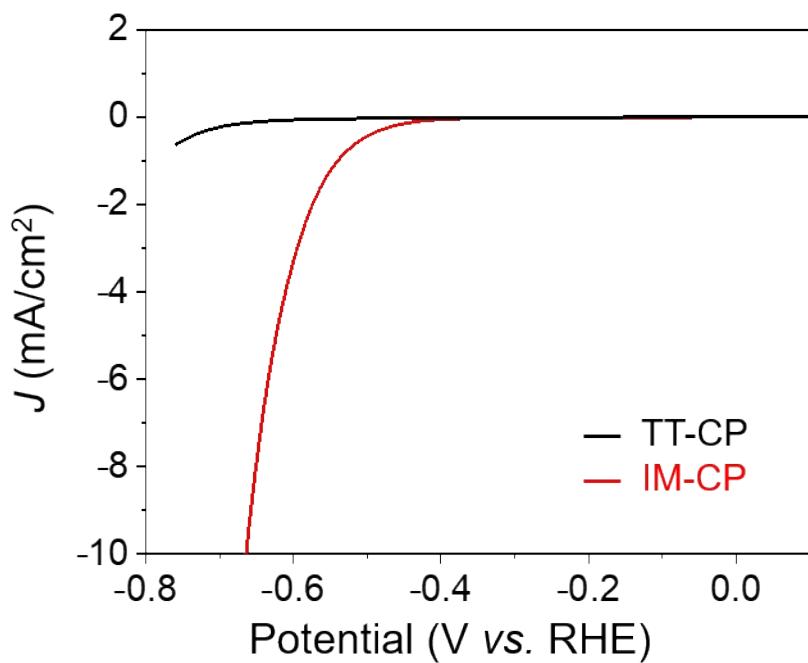


Fig. S7 HER polarization curves of TT-CP and IM-CP

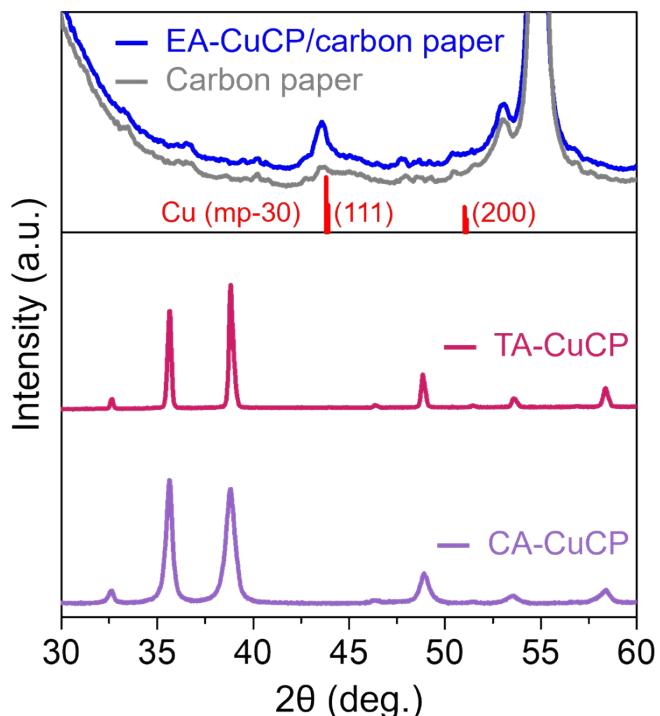


Fig. S8 PXRD patterns of CA-CuCP, TA-CuCP, and EA-CuCP/carbon paper. Inset red vertical lines present reference diffraction patterns of Cu (mp-30), as obtained from the Materials Project.

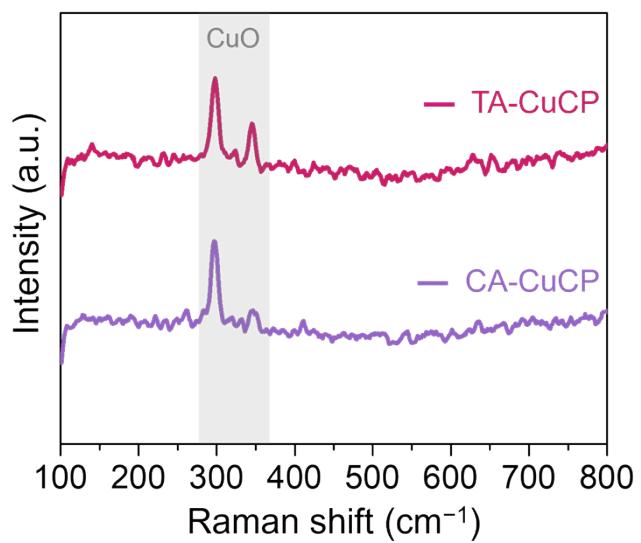


Fig. S9 Raman spectra of CA-CuCP and TA-CuCP.

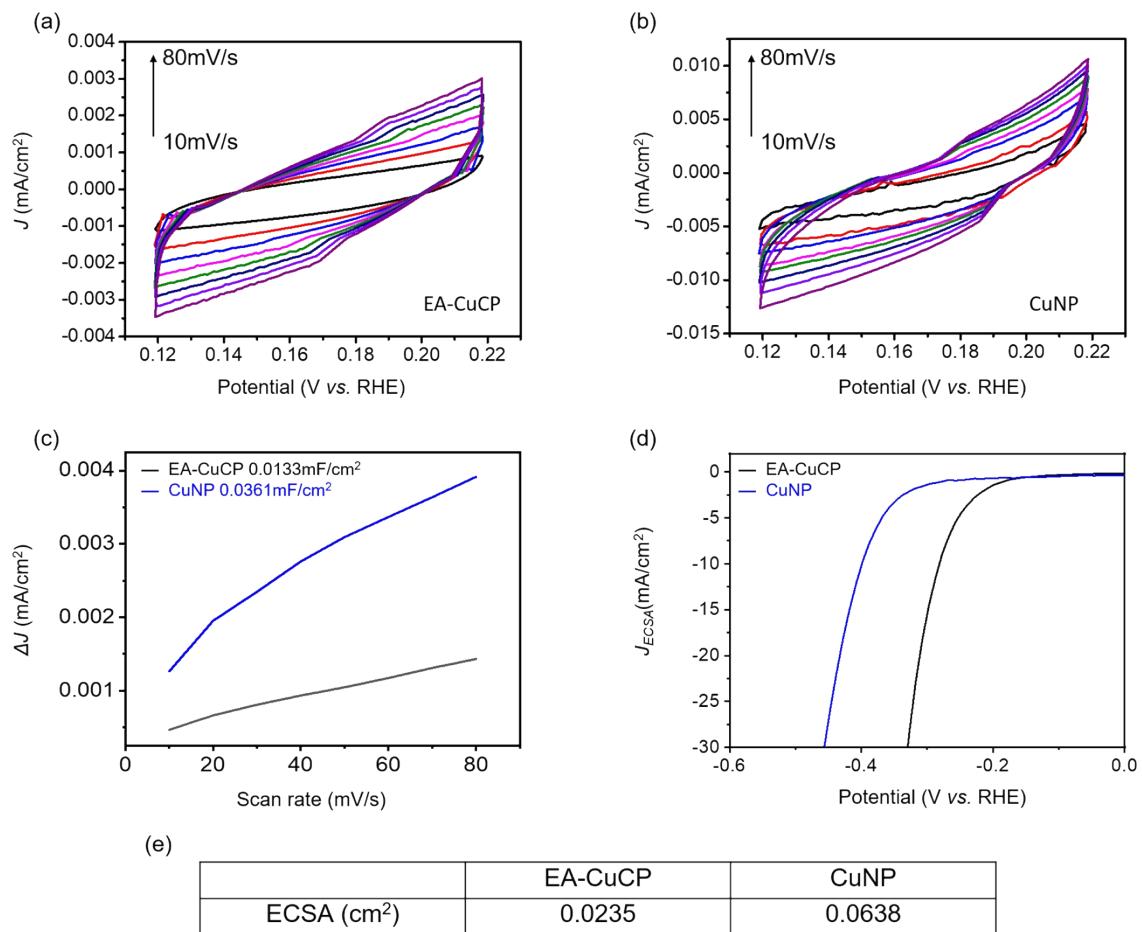


Fig. S10 Cyclic voltammograms (CV) of Cu catalyst at various scan rates in a 0.5 M H₂SO₄ solution: (a) EA-CuCP, (b) CuNP, (c) Average current density ($\Delta j = (j_a - j_c)/2$) against the scan rate showing the double-layer capacitance (C_{dl}) extracted from the corresponding CVs. (d) LSV based on the ECSA-specific current density in a 0.5 M H₂SO₄ solution. (e) The ECSA obtained by C_{dl} measurement was as follows for each catalyst.

The double layer capacitance (C_{dl}) was determined from a CV using the equation: $C_{dl} = \Delta j (j_a - j_c)/2v$, where j_a and j_c are anodic and cathodic current densities at $\Delta E = 0.1$ V and v is the scan rate in mV/s. The non-Faradic current density based electrochemically active surface area (ECSA) was estimated according to the equation: $ECSA = C_{dl}/C_s$, (where C_s denoted specific capacitance and was 20-60 μ F cm⁻² in 0.5 M H₂SO₄). In this study the value is selected as 40 μ F cm⁻².¹ For the measurement, an electrode with a circle-shaped glassy carbon of 0.3 cm in diameter was used at the end of the rod.

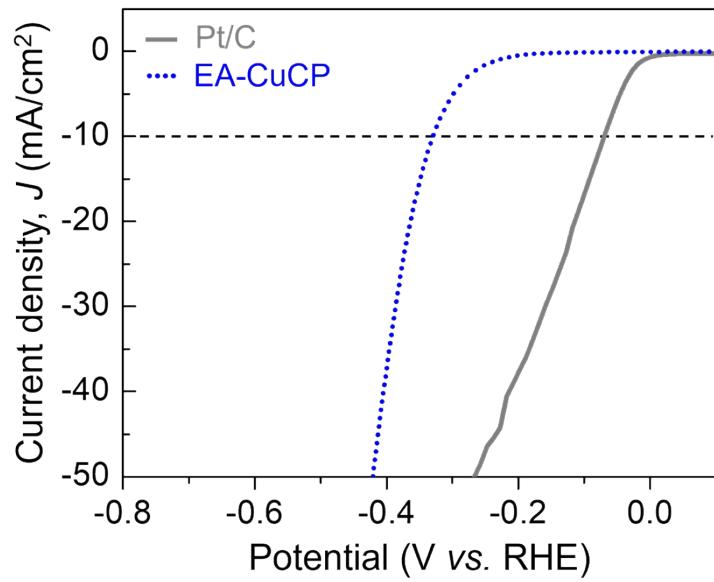


Fig. S11 HER polarization curves of Pt/C and EA-CuCP.

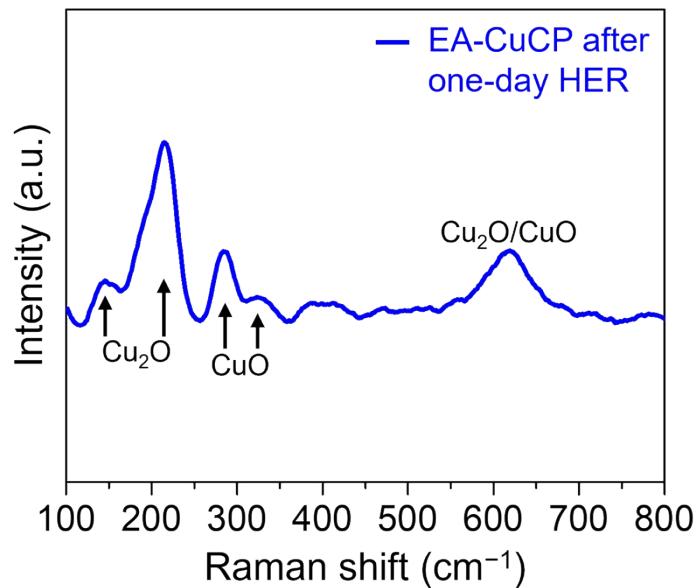


Fig. S12 Raman spectrum of EA-CuCP after the one-day HER stability test.

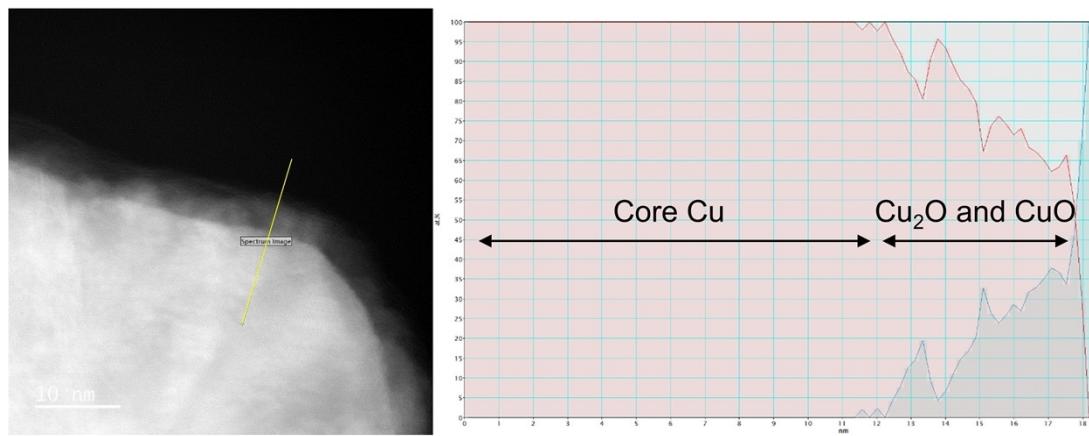


Fig. S13 EDS line profile measured across the boundary of core Cu and surface oxides (Cu_2O and CuO).

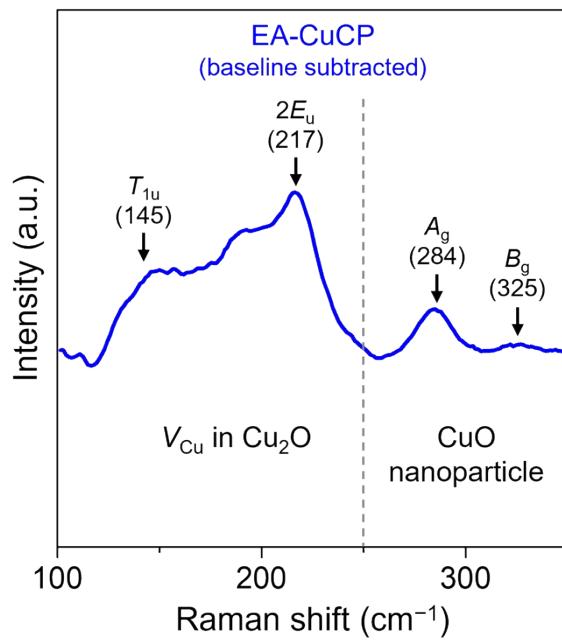


Fig. S14 Magnified and baseline-subtracted Raman spectrum of EA-CuCP.

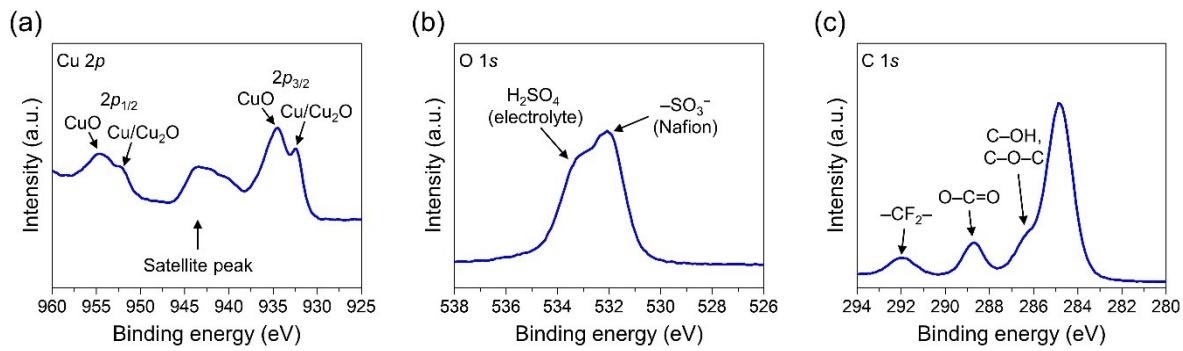


Fig. S15 XPS spectra of EA-CuCP measured at the core level region of (a) Cu 2p, (b) O 1s, and (c) C 1s.

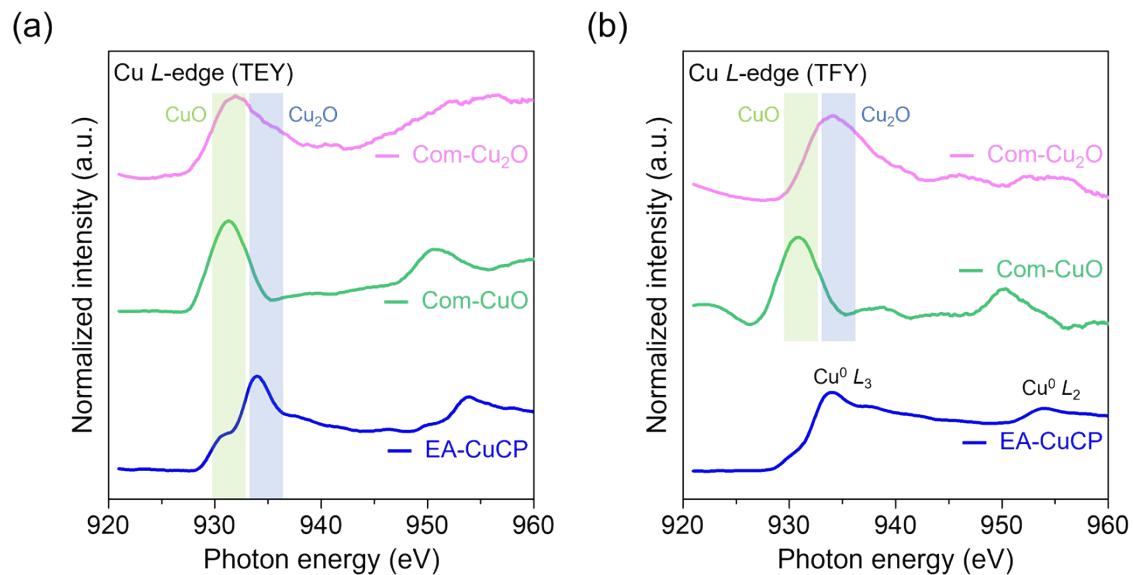


Fig. S16 Cu L-edge NEXAFS spectra of Com-Cu₂O, Com-CuO and EA-CuCP recorded by (a) TEY and (b) TFY detection modes.

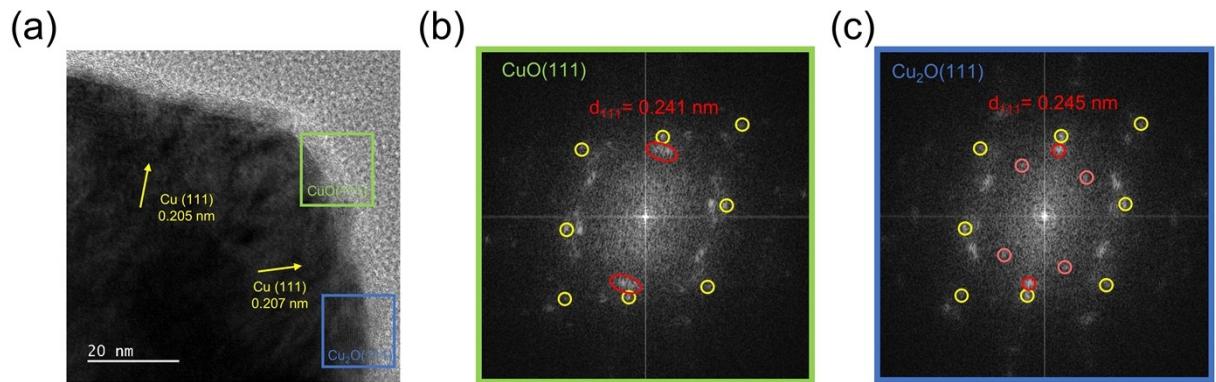


Fig. S17 (a) HR-TEM image of EA-CuCP. FFT patterns obtained at (b) CuO-rich region and (c) Cu₂O-rich region.

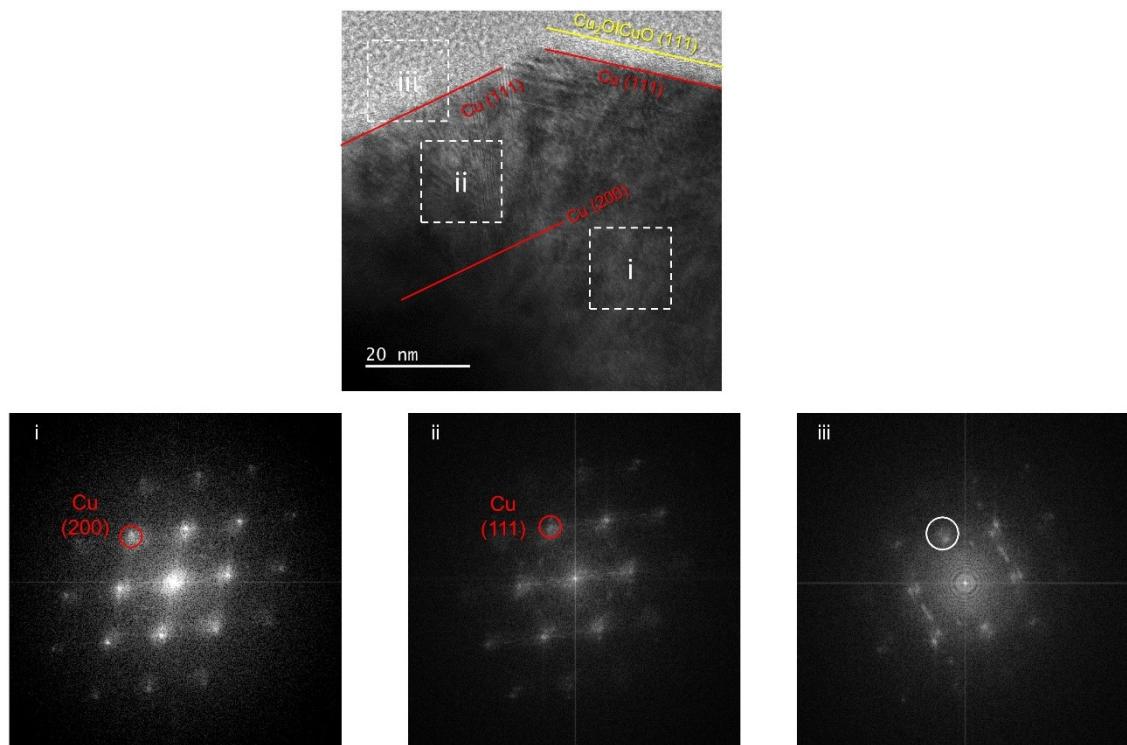


Fig. S18 HR-TEM image and FFT patterns of EA-CuCP measured at three different regions.

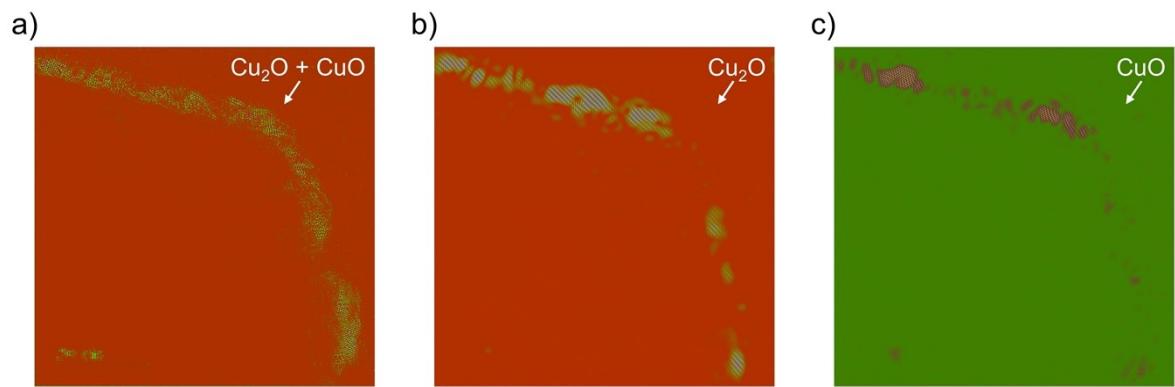


Fig. S19 Inverse FFT patterns of EA-CuCP with lattice fringes of (a) both Cu_2O and CuO , (b) Cu_2O , and (c) CuO highlighted.

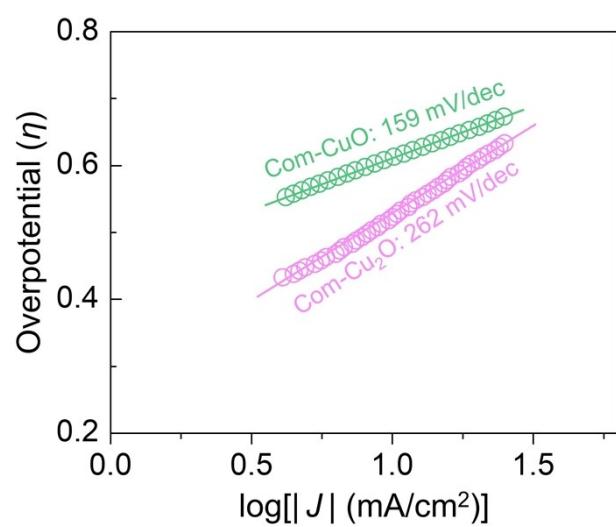


Fig. S20 Tafel slopes of commercial copper oxides including Com- Cu_2O and Com-CuO.

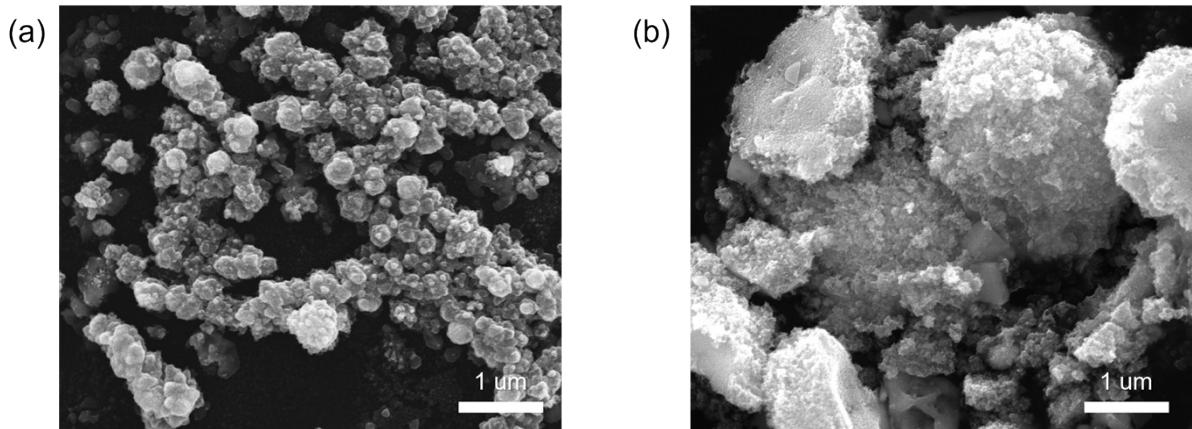


Figure S21. SEM images of EA-CuCP (a) before and (b) after (under -20 mA/cm², 2800 h) the stability test.

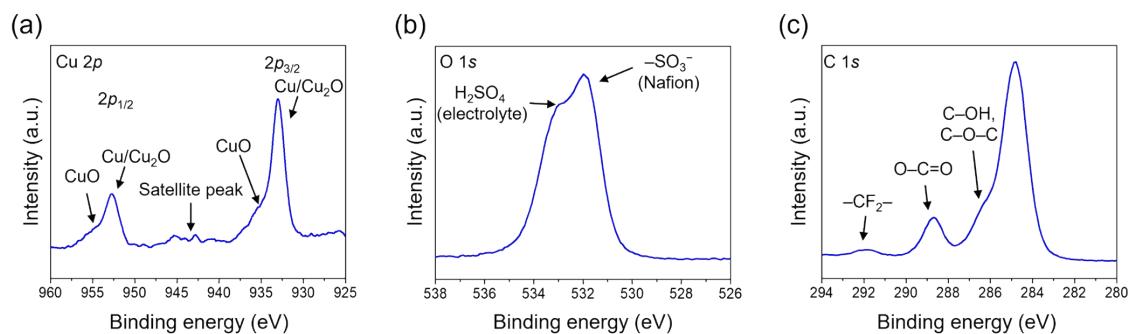


Figure S22. XPS spectra of EA-CuCP after stability test (under -20 mA/cm², 2800 h). (a) Cu 2p, (b) O 1s, and (c) C 1s.

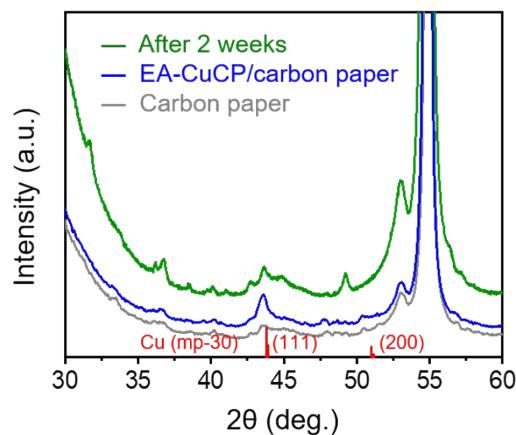


Figure S23. XRD pattern of EA-CuCP after stability test (under -20 mA/cm², 2 weeks).

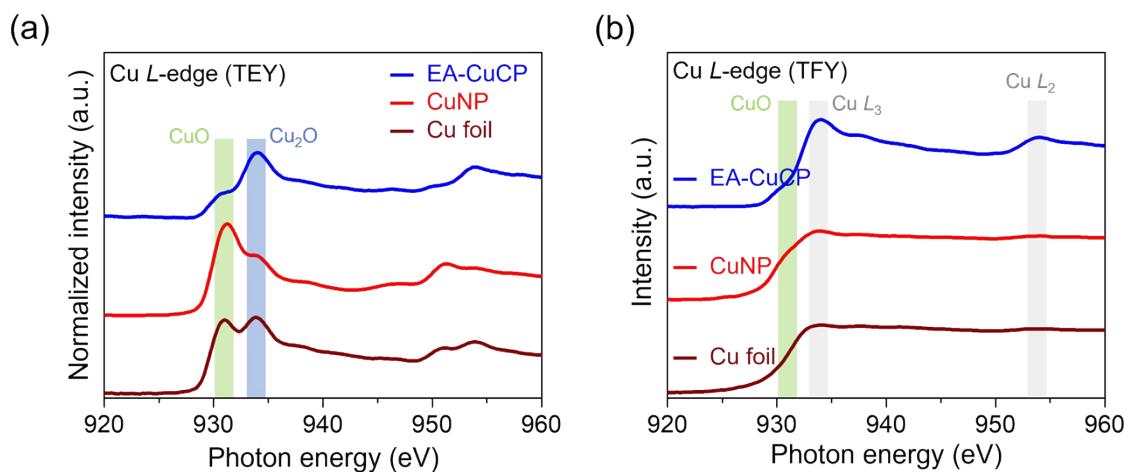


Fig. S24 Cu L -edge NEXAFS spectra of Cu foil, CuNP, and EA-CuCP recorded using the TFY detection mode.

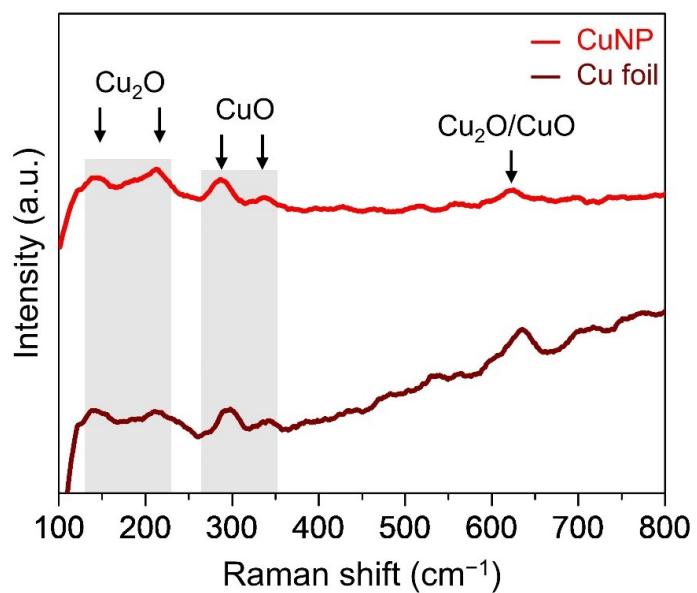


Fig. S25 Raman spectra of Cu foil and CuNP.

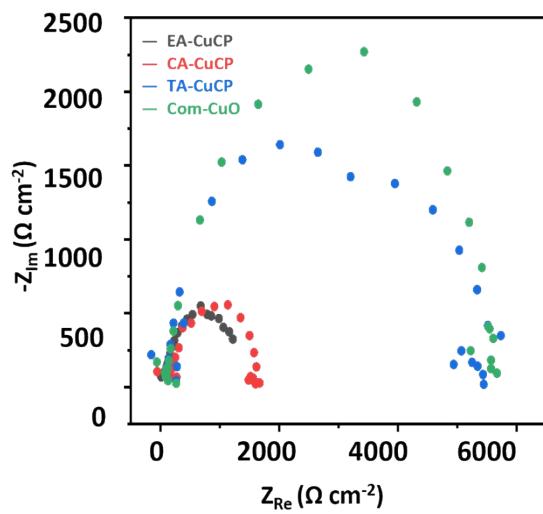


Fig. S26 Electrochemical impedance spectroscopy analysis of copper-based materials.

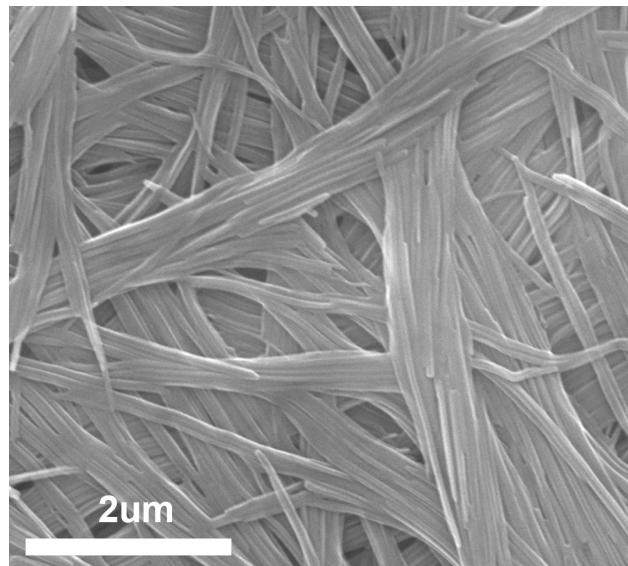


Fig. S27 SEM image of a TT-CP-mod (Cu:S=1:1)

Supplementary Tables

Sample	Space group	Lattice parameters	R _{exp} (%)	R _{wp} (%)	R _p (%)	Goodness of fitting
TT-CP	R-3	a (Å) 19.7045 c (Å) 31.6978	6.28	8.66	6.73	1.38

Table S1 Fitting parameters for the Rietveld refinement of TT-CP.

Table S2 Elemental composition of as-synthesized TT-CP.

Element	Composition (at%)
C	61.76
Cl	4.67
Cu	6.02
N	17.56
O	1.61
S	8.38

Table S3 HER performance of previously reported copper-based catalysts.

	HER overpotential	Stability	Electrolyte	Reference
Cu-Cu ₂ ONP@C	672 mV@-10 mA cm ⁻²	-	0.4 M H ₂ SO ₄	[1]
Pure Cu ₂ O	549 mV@-10 mA cm ⁻²	-	0.5 M H ₂ SO ₄	[2]
Cu ₂ O@rGO	458 mV@-10 mA cm ⁻²	-	0.5 M H ₂ SO ₄	[2]
Cu-Cu ₂ O@C2	637 mV@-10 mA cm ⁻²	-	0.4 M H ₂ SO ₄	[3]
Cu ₂ O-200/GCE	184 mV@-10 mA cm ⁻²	1000 cycles/ 20 h @ -0.57 V	1.0 M KOH	[4]
Cu mesh	622 mV@-10 mA cm ⁻²	-	0.5 M H ₂ SO ₄	[5]
Cu _x O@Cu M400	460 mV@-10 mA cm ⁻²	-	0.5 M H ₂ SO ₄	[5]
Cu _x O@Cu M300	498 mV@-10 mA cm ⁻²	20 h @ -2.5 mA cm ⁻²	0.5 M H ₂ SO ₄	[5]
Plasma spray Cu	182 mV@-10 mA cm ⁻²	30 h @ -0.35 V (100 mA cm ⁻²)	0.5 M H ₂ SO ₄	[6]
Cu/Cu ₂ O- CuO/rGO-400	105 mV@-10 mA cm ⁻²	15 h @ -10 mA cm ⁻²	1.0 M KOH	[7]
EA-CuCP	331 mV@-10 mA cm ⁻²	2,800 hr @ -20 mA cm ⁻²	0.5 M H ₂ SO ₄	This work

Supplementary References

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